

**SIEMENS**

# DUAL CHANNEL ILD255

## Bidirectional Input Optocoupler

## FEATURES

- AC or Polarity Insensitive Inputs
  - Continuous Forward Current, 130 mA
  - Applications—Telecommunications
    - Ring Detection
    - Loop Current Detector
  - Built-in Reverse Polarity Input Protection
  - Improved CTR Symmetry
  - Industry Standard DIP Package
  - Underwriters Lab File #E52744
  -  VDE 0884 Available with Option 1

## **DESCRIPTION**

The ILD255 is a bidirectional input optically coupled isolator consisting of two high current Gallium Arsenide infrared LEDs coupled to a silicon NPN phototransistor per channel. The ILD255 has a minimum CTR of 50%

These optocouplers are ideal for applications requiring AC signal detection and monitoring.

#### **Maximum Ratings (Each Channel)**

## Emitter

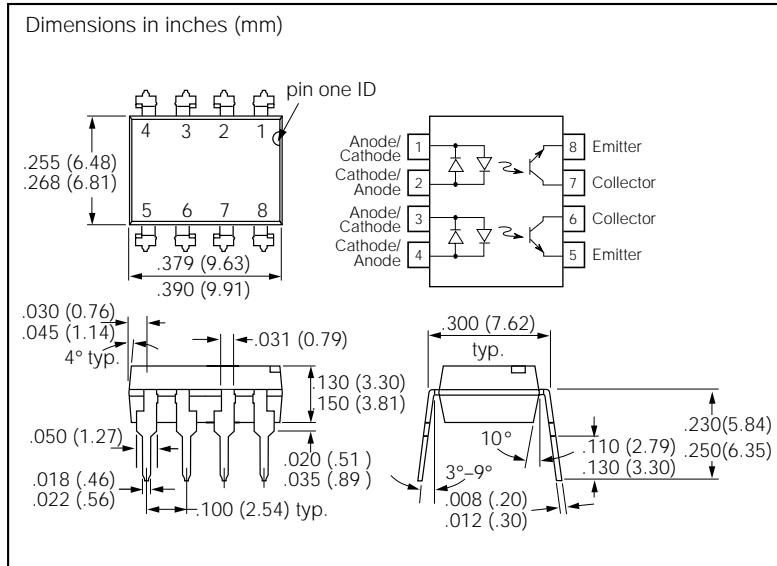
Peak Pulsed Current (1 µs, 300 pps) ..... 3 A  
Continuous Forward Current ..... 130 mA RMS  
Power Dissipation at 25°C ..... 175 mW  
Derate Linearly from 25°C ..... 2.3 mW/°C

## Detector

Collector-Emitter Breakdown Voltage..... 30 V  
Emitter-Base Breakdown Voltage..... 5 V  
Power Dissipation at 25°C ..... 200 mW  
Derate Linearly from 25°C..... 2.6 mW/°C

## Package

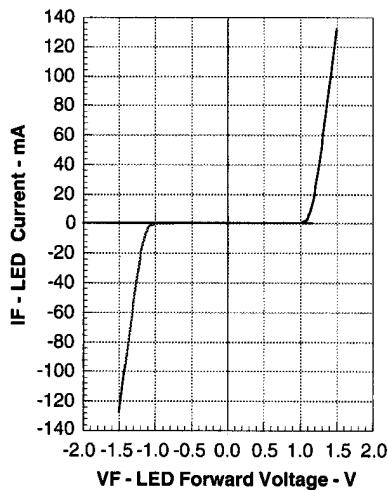
|   |                             |
|---|-----------------------------|
| Isolation Test Voltage (between emitter<br>and detector referred to standard<br>climate 23°C/50%RH,<br>DIN 50014) ..... | 5300 VAC <sub>RMS</sub>     |
| Creepage .....  | min. 7 mm                   |
| Clearance.....  | min. 7 mm                   |
| Isolation Resistance  |                             |
| $V_{IO}=500\text{ V}, T_A=25^\circ\text{C}$ .....   | $R_{IO}\geq 10^{12} \Omega$ |
| $V_{IO}=500\text{ V}, T_A=100^\circ\text{C}$ .....  | $R_{IO}\geq 10^{11} \Omega$ |
| Total Dissipation at 25°C .....   | 400 mW                      |
| Derate Linearly from 25°C .....   | 5.3 mW/°C                   |
| Storage Temperature .....   | -55°C to +150°C             |
| Operating Temperature .....   | -55°C to +100°C             |
| Lead Soldering Time at 260°C .....  | 10 sec                      |



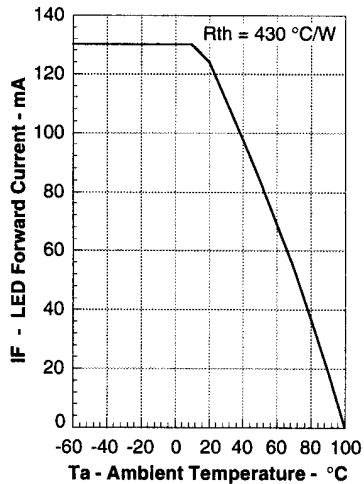
## **Electrical Characteristics $T_A=25^\circ C$**

| Parameter                 | Mln.  | Typ. | Max. | Unit | Condition  |
|---------------------------|---|------|------|------|--|
| <b>Emitter</b>            |   |      |      |      |  |
| Forward Voltage $V_F$     |   | 1.2  | 1.5  | V    | $I_F = \pm 10 \text{ mA}$                              |
| <b>Detector</b>           |   |      |      |      |  |
| $BV_{CEO}$                | 30  | 50   |      | V    | $I_C = 10 \text{ mA}$                                  |
| $BV_{ECO}$                | 7   | 10   |      | V    | $I_E = 10 \mu\text{A}$                                 |
| $I_{CEO}$                 |   | 5    | 50   | nA   | $V_{CE} = 10 \text{ V}$                                |
| <b>Package</b>            |   |      |      |      |  |
| $V_{CESat}$               |   |      | 0.4  | V    | $I_F = \pm 16 \text{ mA}$ ,<br>$I_C = 2 \text{ mA}$    |
| DC Current Transfer Ratio | 50  |      |      | %    | $I_F = \pm 10 \text{ mA}$ ,<br>$V_{CE} = 10 \text{ V}$ |
| Symmetry                  | $\frac{\text{CTR at } +10 \text{ mA}}{\text{CTR at } -10 \text{ mA}}$ |      | 0.50 | 1.0  | 2.0  |

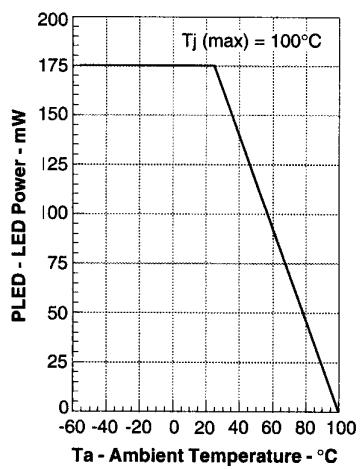
**Figure 1. LED forward current versus forward voltage**



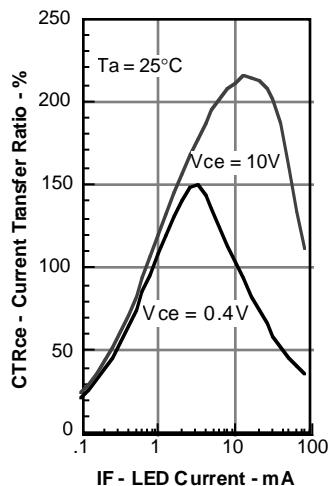
**Figure 2. Maximum LED current versus ambient temperature**



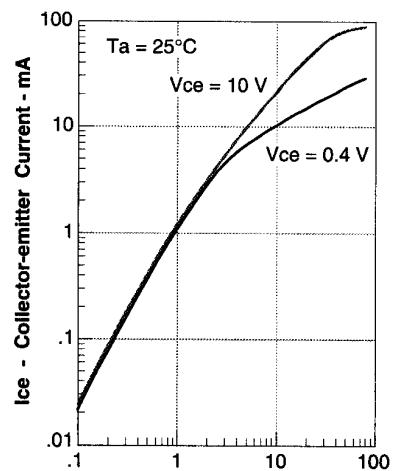
**Figure 3. Maximum LED power dissipation**



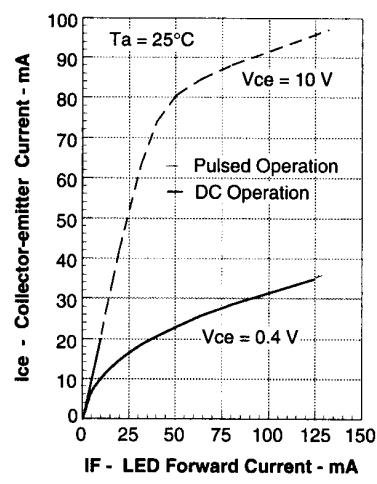
**Figure 4. Current transfer ratio versus LED current and collector-emitter voltage**



**Figure 6. Saturated and nonsaturated collector-emitter current versus LED current**



**Figure 5. Saturated and nonsaturated collector-emitter current versus LED current**



**Figure 7. Collector emitter current versus collector emitter voltage**

